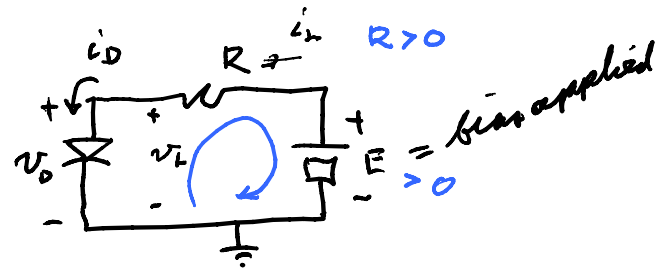
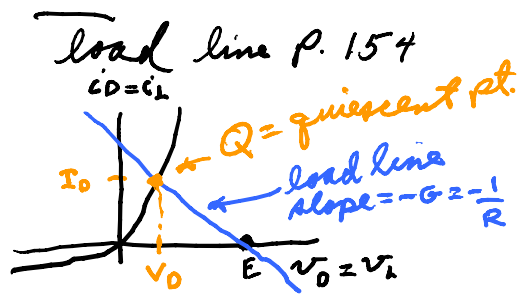


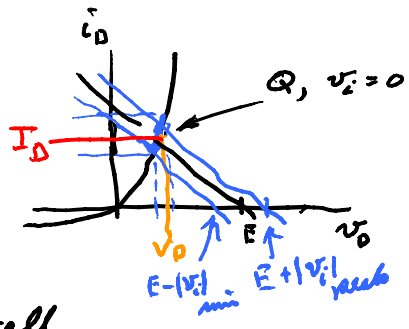
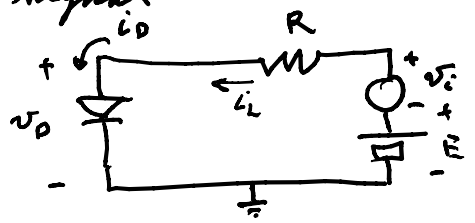
For next time: appendix B, pp. B-1 through B-7
 BJT biasing, pp. 432-436
 BJT hybrid π , p. 488

EE 303
 02/02/10



KVL: $-v_L - Ri_L + E = 0 \Rightarrow i_L = \frac{E - v_L}{R}$
 KVL: $v_L = v_D$
 KCL: $i_D = i_L$

Put in signal



want to know changes in i_D , call this signal current, i_s , when v_i changes
 i.e. desire current due to signal.

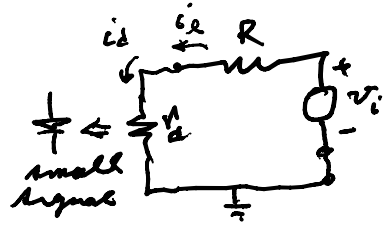
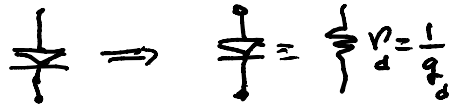
$i_D = I_D + i_s$; $i_D = \text{total current}$
 $I_D = \text{bias current}$
 $i_s = \text{signal current}$

$v_D = V_D + v_s$

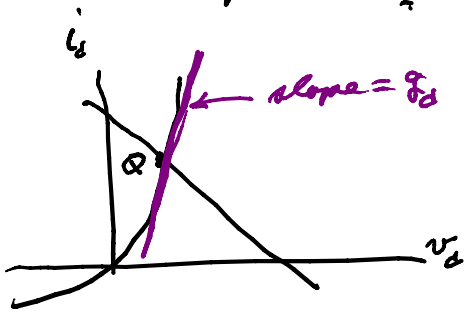
$i_D = f(v_D)$ make a Taylor series expansion about $V_D = V_D$
 $= f(V_D) + \left. \frac{df(v_D)}{dv_D} \right|_{v_D=V_D} (v_D - V_D) + \frac{1}{2!} \left. \frac{d^2 f(v_D)}{dv_D^2} \right|_{v_D=V_D} (v_D - V_D)^2 + \dots$
 ignore if small signal

$i_D - f(V_D) = i_D - I_D = i_s$
 $v_D - V_D = v_s$
 $i_s = \left. \frac{df(v_D)}{dv_D} \right|_Q \cdot v_s = g_s \cdot v_s$

for small signal



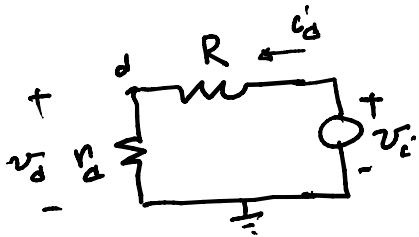
equivalent circuit for small signals



$$i_L = I_L + i_L \Rightarrow i_L - I_L = i_L$$

by KCL = i_d

can analyze for small signal behavior



$$(R + r_d) i_d = v_i$$

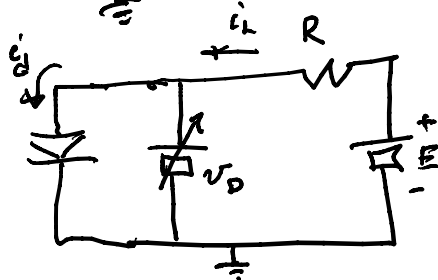
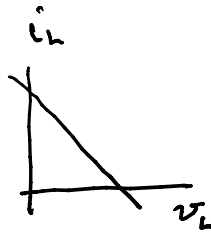
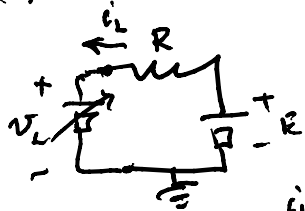
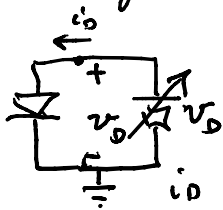
$$i_d = \frac{v_i}{R + r_d}$$

$$v_d = \frac{r_d}{R + r_d} v_i$$

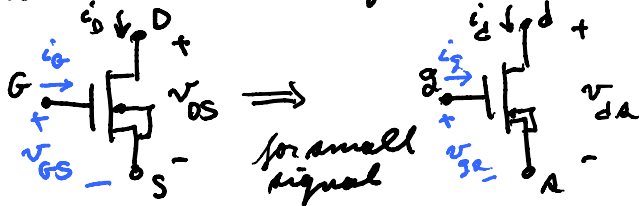
power into v_i :

$$v_i (-i_d) = -\frac{v_i^2}{R + r_d}$$

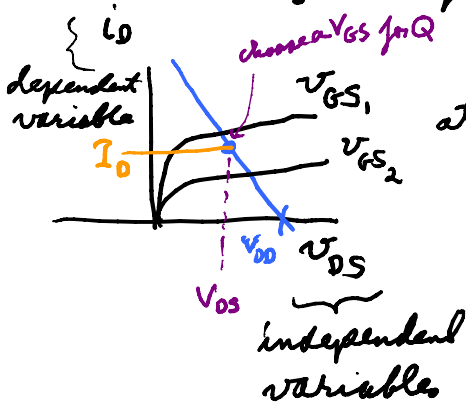
To find the Q point in SPICE



Equivalent circuit for a transistor NMOS



for small signal



at DC $i_G = 0 \Rightarrow i_g = 0$ if near DC

$$v_{DS} = V_{DS} + v_{da}$$

$$i_D = I_D + i_d$$

$$Q = (V_{GS}, V_{DS})$$

= bias point of transistor

$$v_{GS} = V_{GS} + v_{gs}$$

$$i_D = f(v_{GS}, v_{DS}) = f(V_{GS}, V_{DS}) + \frac{\partial i_D}{\partial v_{GS}} \Big|_Q (v_{GS} - V_{GS}) + \frac{\partial i_D}{\partial v_{DS}} \Big|_Q (v_{DS} - V_{DS}) + \frac{1}{2!} \frac{\partial^2 i_D}{\partial v_{GS}^2} \Big|_Q (v_{GS} - V_{GS})^2 + \frac{1}{2!} \frac{\partial^2 i_D}{\partial v_{DS}^2} \Big|_Q (v_{DS} - V_{DS})^2 + \frac{\partial^2 i_D}{\partial v_{GS} \partial v_{DS}} \Big|_Q (v_{GS} - V_{GS})(v_{DS} - V_{DS}) + \dots$$

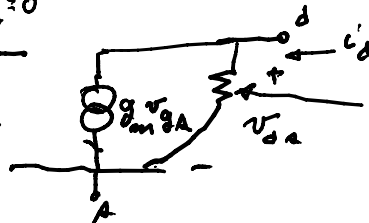
Throw away for small signals

$$i_d = g_m v_{gs} + g_d v_{ds}$$

$$i_g = 0$$



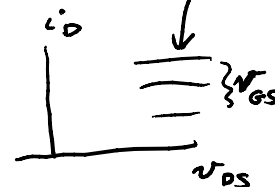
$$i_g = 0$$



$r_d = \frac{1}{g_d}$ = drain resistance

To find these parameters, g_m & g_d , when in saturation

$$i_D = \frac{K_P}{2} \cdot \frac{W}{L} (v_{GS} - V_{T0})^2 (1 + \lambda v_{DS})$$



$$\begin{aligned}
 \text{for } g_m &= \left. \frac{\partial i_D}{\partial v_{GS}} \right|_{v_{DS}=v_{DS}, v_{GS}=v_{GS}} = 2 \left(\frac{\mu_n C_{ox}}{2} \frac{W}{L} \right) (v_{GS} - V_{TO}) (1 + \lambda v_{DS}) \Big|_Q \\
 &= 2 \cdot \frac{i_D}{(v_{GS} - V_{TO})} \Big|_Q = 2 \cdot \frac{I_D}{(V_{GS} - V_{TO})}
 \end{aligned}$$

$$\text{for } g_d = \left. \frac{\partial i_D}{\partial v_{DS}} \right|_Q = \frac{\mu_n C_{ox}}{2} \frac{W}{L} (v_{GS} - V_{TO})^2 \cdot \lambda \Big|_Q \approx I_D \cdot \lambda$$

